

Quantum Spin Hall Effect

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The quantum Hall liquid is a novel state of matter with profound emergent properties such as fractional charge and statistics. Existence of the quantum Hall effect requires breaking of the time reversal symmetry caused by an external magnetic field. In this work, we predict a quantized spin Hall effect in the absence of any magnetic field, where the intrinsic spin Hall conductance is quantized in units of $2\frac{e}{4\pi}$. The degenerate quantum Landau levels are created by the spin-orbit coupling in conventional semiconductors in the presence of a strain gradient. This new state of matter has many profound correlated properties described by a topological field theory.

Recently, the intrinsic spin Hall effect has been theoretically predicted for semiconductors with spin-orbit coupled band structures[1, 2]. The spin Hall current is induced by the external electric field according to the equation

$$j_j^i = \sigma_s \epsilon_{ijk} E_k \quad (1)$$

where j_j^i is the spin current of the i -th component of the spin along the direction j , E_k is the electric field and ϵ_{ijk} is the totally antisymmetric tensor in three dimensions. The spin Hall effect has recently been detected in two different experiments[3, 4], and there is strong indication that at least one of them is in the intrinsic regime[5]. Because both the electric field and the spin current are even under time reversal, the spin current could be dissipationless, and the value of σ_s could be independent of the scattering rates. This is in sharp contrast with the extrinsic spin Hall effect, where the effect arises only from the Mott scattering from the impurity atoms[6].

The independence of the intrinsic spin Hall conductance σ_s on the impurity scattering rate naturally raises the question whether it can be quantized under certain conditions, similar to the quantized charge Hall effect. We start off our analysis with a question: Can we have Landau Level (LL)-like behavior *in the absence* of a magnetic field [7]? The quantum Landau levels arise physically from a *velocity dependent force*, namely the Lorentz force, which contributes a term proportional to $\vec{A} \cdot \vec{p}$ in the Hamiltonian. Here \vec{p} is the particle momentum and \vec{A} is the vector potential, which in the symmetric gauge is given by $\vec{A} = \frac{B}{2}(y, -x, 0)$. In this case, the velocity dependent term in the Hamiltonian is proportional to $B(xp_y - yp_x)$.

In condensed matter systems, the only other ubiquitous velocity dependent force besides the Lorentz force is the spin-orbit coupling force, which contributes a term proportional to $(\vec{p} \times \vec{E}) \cdot \vec{\sigma}$ in the Hamiltonian. Here \vec{E} is the electric field, and $\vec{\sigma}$ is the Pauli spin matrix. Unlike the magnetic field, the presence of an electric field does not break the time reversal symmetry. If we consider the particle momentum confined in a two dimensional geometry, say the xy plane, and the electric field direction confined in the xy plane as well, only the z component of the spin enters the Hamiltonian. Furthermore, if the electric

field \vec{E} is not constant but is proportional to the radial coordinate \vec{r} , as it would be, for example, in the interior of a uniformly charged cylinder $\vec{E} \sim E(x, y, 0)$, then the spin-orbit coupling term in the Hamiltonian takes the form $E\sigma_z(xp_y - yp_x)$. We see that this system behaves in such a way as if particles with opposite spins experience the opposite “effective” orbital magnetic fields, and a Landau level structure should appear for each spin orientations.

However, such an electric field configuration is not easy to realize. Fortunately, the scenario previously described is realizable in zinc-blende semiconductors such as GaAs, where the shear strain gradients can play a similar role. Zinc-blende semiconductors have the point-group symmetry T_d which is half of the cubic-symmetry group O_h , and does not contain inversion as one of its symmetries. Under the T_d point group, the cubic harmonics xyz transform like the identity, and off-diagonal symmetric tensors ($xy + yx$, etc.) transform in the same way as vectors on the other direction (z , etc), and represent basis functions for the T_1 representation of the group. Specifically, strain is a symmetric tensor $\epsilon_{ij} = \epsilon_{ji}$, and its off-diagonal (shear) components are, for the purpose of writing down a spin-orbit coupling Hamiltonian, equivalent to an electric field in the remaining direction:

$$\epsilon_{xy} \leftrightarrow E_z; \quad \epsilon_{xz} \leftrightarrow E_y; \quad \epsilon_{yz} \leftrightarrow E_x \quad (2)$$

The Hamiltonian for the conduction band of bulk zinc-blende semiconductors under strain is hence the analogous to the spin-orbit coupling term $(\vec{v} \times \vec{E}) \cdot \vec{\sigma}$. In addition, we have the usual kinetic p^2 term and a trace of the strain term $\text{tr}\epsilon = \epsilon_{xx} + \epsilon_{yy} + \epsilon_{zz}$, both of which transform as the identity under T_d :

$$H = \frac{p^2}{2m} + B\text{tr}\epsilon + \frac{1}{2} \frac{C_3}{\hbar} [(\epsilon_{xy}p_y - \epsilon_{xz}p_z)\sigma_x + (\epsilon_{zy}p_z - \epsilon_{xy}p_x)\sigma_y + (\epsilon_{zx}p_x - \epsilon_{yz}p_y)\sigma_z] \quad (3)$$

For GaAs, the constant $\frac{C_3}{\hbar} = 8 \times 10^5 \text{m/s}$ [8]. This Hamiltonian is not new and was previously written down in Ref. [9, 10, 11, 12] but the analogy with the electric field and its derivation from a Lorentz force is suggestive enough to warrant repetition. There is yet another term allowed by group theory in the Hamiltonian [13], but this is higher

order in perturbation theory and hence not of primary importance.

Let us now presume a strain configuration in which $\epsilon_{xy} = 0$ but ϵ_{xz} has a constant gradient along the y direction while ϵ_{yz} has a constant gradient along the x direction. This case then mimics the situation of the electric field inside a uniformly charged cylinder discussed above, as $\epsilon_{xz}(\leftrightarrow E_y) = gy$ and $\epsilon_{yz}(\leftrightarrow E_x) = gx$, g being the magnitude of the strain gradient. With this strain configuration and in a symmetric quantum well in the xy plane, which we approximate as being parabolic, the above Hamiltonian becomes:

$$H = \frac{p_x^2 + p_y^2}{2m} + \frac{1}{2} \frac{C_3}{\hbar} g (yp_x - xp_y) \sigma_z + D(x^2 + y^2) \quad (4)$$

We first solve this Hamiltonian and come back to the experimental realization of the strain architecture in the later stages of the paper. We make the coordinate change $x \rightarrow (2mD)^{-1/4}x$, $y \rightarrow (2mD)^{-1/4}y$ and $R = \frac{1}{2} \frac{C_3}{\hbar} \sqrt{\frac{2m}{D}} g$. $R = 2$ or $D = D_0 \equiv \frac{2mgC_3^2}{16\hbar^2}$ is a special point, where the Hamiltonian can be written as a complete square, namely $H = \frac{1}{2m} (\vec{p} - e\vec{A}\sigma_z)^2$ with $\vec{A} = \frac{mC_3g}{2\hbar e} (y, -x, 0)$. At this point, our Hamiltonian is exactly equivalent to the usual Hamiltonian of a charged particle in a uniform magnetic field, where the two different spin directions experience the opposite directions of the “effective” magnetic field. Any generic confining potential $V(x, y)$ can be written as $D_0(x^2 + y^2) + \Delta V(x, y)$, where the first term completes the square for the Hamiltonian, and the second term $\Delta V(x, y) = V(x, y) - D_0(x^2 + y^2)$ describes the additional static potential within the Landau levels. Since $[H, \sigma_z] = 0$ we can use the spin on the z direction to characterize the states. In the new coordinates, the Hamiltonian takes the form:

$$H = \begin{pmatrix} H_\uparrow & 0 \\ 0 & H_\downarrow \end{pmatrix}$$

$$H_{\downarrow, \uparrow} = \sqrt{\frac{D}{2m}} [p_x^2 + p_y^2 + x^2 + y^2 \pm R(xp_y - yp_x)] \quad (5)$$

The $H_{\downarrow, \uparrow}$ is the Hamiltonian for the down and up spin σ_z respectively. Working in complex-coordinate formalism and choosing $z = x + iy$ we obtain two sets of raising and lowering operators:

$$\begin{aligned} a &= \partial_{z^*} + \frac{z}{2}, & a^\dagger &= -\partial_z + \frac{z^*}{2} \\ b &= \partial_z + \frac{z^*}{2}, & b^\dagger &= -\partial_{z^*} + \frac{z}{2} \end{aligned} \quad (6)$$

in terms of which the Hamiltonian decouples:

$$H_{\downarrow, \uparrow} = 2\sqrt{\frac{D}{2m}} \left[\left(1 \mp \frac{R}{2}\right) aa^\dagger + \left(1 \pm \frac{R}{2}\right) bb^\dagger + 1 \right] \quad (7)$$

The eigenstates of this system are harmonic oscillators $|m, n\rangle = (a^\dagger)^m (b^\dagger)^n |0, 0\rangle$ of energy $E_{m, n}^{\downarrow, \uparrow} =$

$\frac{1}{2} \sqrt{\frac{D}{2m}} \left[\left(1 \mp \frac{R}{2}\right)m + \left(1 \pm \frac{R}{2}\right)n + 1 \right]$. We shall focus on the case of $R = 2$ where there is no additional static potential within the Landau level.

For the spin up electron, the vicinity of $R \approx 2$ is characterized by the Hamiltonian $H_\uparrow = \frac{1}{2} \frac{C_3}{\hbar} g (2aa^\dagger + 1)$ with the LLL wave function $\phi_n^\uparrow(z) = \frac{z^n}{\sqrt{\pi n!}} \exp(-\frac{zz^*}{2})$. a is the operator moving between different Landau levels, while b is the operator moving between different degenerate angular momentum states within the same LL: $L_z = bb^\dagger - aa^\dagger$, $L_z \phi_n^\uparrow(z) = n \phi_n^\uparrow(z)$. The wave function, besides the confining factor, is holomorphic in z , as expected. These up spin electrons are the chiral, and their charge conductance is quantized in units of e^2/h .

For the spin down electron, the situation is exactly the opposite. The vicinity of $R \approx 2$ is characterized by the Hamiltonian $H_\downarrow = \frac{1}{2} \frac{C_3}{\hbar} g (2bb^\dagger + 1)$ with the LLL wave function $\phi_m^\downarrow(z) = \frac{(z^*)^m}{\sqrt{\pi m!}} \exp(-\frac{zz^*}{2})$. b is the operator moving between different Landau levels, while a is the operator between different degenerate angular momentum states within the same LL: $L_z = bb^\dagger - aa^\dagger$, $L_z \phi_m^\downarrow(z) = -m \phi_m^\downarrow(z)$. The wave function, besides the confining factor, is anti-holomorphic in z . These down spin electrons are anti-chiral, and their charge conductance is quantized in units of $-e^2/h$.

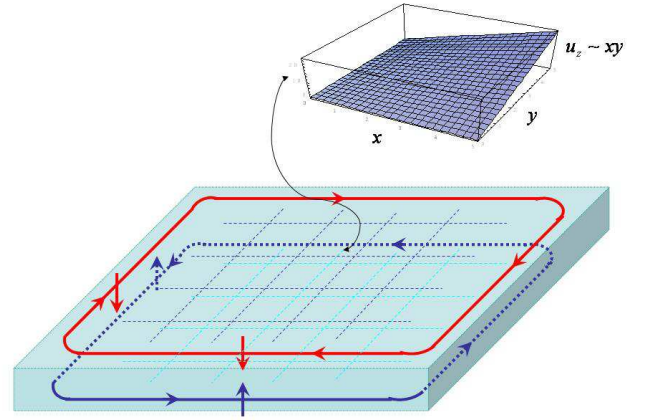


FIG. 1: Spin up and down electrons have opposite chirality as they feel the opposite spin-orbit coupling force. Total charge conductance vanishes but spin conductance is quantized. The inset shows the lattice displacement leading to the strain configuration.

The picture that now emerges is the following: our system is equivalent to a bilayer system; in one of the layers we have spin down electrons in the presence of a down-magnetic field whereas in the other layer we have spin up electrons in the presence of an up-magnetic field. These two layers are placed together. The spin up electrons have positive charge Hall conductance while the

spin down electrons have negative charge Hall conductance. As such, the charge Hall conductance of the whole system vanishes. The time reversal symmetry reverses the directions of the “effective” orbital magnetic fields, but interchanges the layers at the same time. However, the spin Hall conductance remains finite, as the chiral states are spin-up while the anti-chiral states are spin-down, as shown in Figure[1]. The spin Hall conductance is hence quantized in units of $2\frac{e^2}{h}\frac{\hbar}{2e} = 2\frac{e}{4\pi}$. Since an electron with charge e also carries spin $\hbar/2$, a factor of $\frac{\hbar}{2e}$ is used to convert charge conductance into the spin conductance.

While it is hard to experimentally measure the spin Hall effect, and supposedly even harder to measure the quantum version of it, the measurement of the charge quantum Hall effect has become relatively common. In our system, however, the charge Hall conductance σ_{xy} vanishes by symmetry. However, we can use our physical analogy of the two layer system placed together. In each of the layers we have a charge Quantum Hall effect at the same time (since the filling is equal in both layers), but with opposite Hall conductance. However, when on the plateau, the longitudinal conductance σ_{xx} also vanishes ($\sigma_{xx} = 0$) separately for the spin-up and spin-down electrons, and hence vanishes for the whole system. Of course, between plateaus it will have non-zero spikes (narrow regions). This is the easiest detectable feature of the new state, as the measurement is entirely electric. Other experiments on the new state could involve the injection of spin-polarized edge states, which would acquire different chirality depending on the initial spin direction.

We now discuss the realization of a strain gradient of the specific form proposed in this paper. The strain tensor is related to the displacement of lattice atoms from their equilibrium position u_i in the familiar way $\epsilon_{ij} = (\partial u_i / \partial x_j + \partial u_j / \partial x_i) / 2$. Our strain configuration is $\epsilon_{xx} = \epsilon_{yy} = \epsilon_{zz} = \epsilon_{xy} = 0$ as well as the strain gradients $\epsilon_{zx} = gy$ and $\epsilon_{yx} = gx$. Having the diagonal strain components non-zero will not change the physics as they add only a chemical potential term to the Hamiltonian. The above strain configuration corresponds to a displacement of atoms from their equilibrium positions of the form $\vec{u} = (0, 0, 2gxy)$. This can be possibly realized by pulverizing GaAs on a substrate in MBE at a rate which is a function of the position of the pulverizing beam on the substrate. The GaAs pulverization rate should vary as $xy \sim r^2 \sin(2\phi)$, where r is the distance from one of the corners of the sample where the GaAs depositing was started. Conversely, we can keep the pulverizing beam fixed at some r and rotate the sample with an angle-dependent angular velocity of the form $\sin(2\phi)$. We then move to the next incremental distance r , increase the beam rate as r^2 and again start rotating the substrate as the depositing procedure is underway.

The strain architecture we have proposed to realize the Quantum Spin Hall effect is by no means unique. In the

present case, we have re-created the so-called symmetric gauge in magnetic-field language, but, with different strain architectures, one can create the Landau gauge Hamiltonian and indeed many other gauges. The Landau gauge Hamiltonian is maybe the easiest to realize in an experimental situation, by growing the quantum well in the [110] direction. This situation creates an off-diagonal strain $\epsilon_{xy} = \frac{1}{4}S_{44}T$, and $\epsilon_{xz} = \epsilon_{yz} = 0$ where T is the lattice mismatch (or impurity concentration), s_{44} is a material constant and x, y, z are the cubic axes. The spin-orbit part of the Hamiltonian is now $\frac{C_3}{\hbar}\epsilon_{xy}(p_x\sigma_y - p_y\sigma_x)$. However, since the growth direction of the well is [110] we must make a coordinate transformation to the x', y', z' coordinates of the quantum well (x', y' are the new coordinates in the plane of the well, whereas z' is the growth coordinate, perpendicular to the well and identical to the [110] direction in cubic axes). The coordinate transformation reads: $x' = \frac{1}{\sqrt{2}}(x - y)$, $y' = -z$, $z' = \frac{1}{\sqrt{2}}(x + y)$, and the momentum along z' is quantized. We now vary the impurity concentration T (or vary the speed at which we deposit the layers) linearly on the y' direction of the quantum well so that $\epsilon_{xy} = gy'$ where g is strain gradient, linearly proportional to the gradient in T . In the new coordinates and for this strain geometry, the Hamiltonian reads:

$$H = \frac{p^2}{2m} + \frac{C_3}{\hbar}gy'p_{x'}\sigma_{z'} + Dy^2 \quad (8)$$

where we have added a confining potential. At the suitable match between D and g , this is the Landau-gauge Hamiltonian. One can also replace the soft-wall condition (the Harmonic potential) by hard-wall boundary condition.

We now estimate the Landau Level gap and the strain gradient needed for such an effect, as well as the strength of the confining potential. In the case $R \approx 2$ the energy difference between Landau levels is $\Delta E_{Landau} = 2 \times \hbar \frac{1}{2} \frac{C_3}{\hbar} g = C_3 g$. For a gap of $1mK$, we hence need a strain gradient or 1% over $60\mu m$. Such a strain gradient is easily realizable experimentally, but one would probably want to increase the gap to $10mK$ or more, for which a strain gradient of 1% over $6\mu m$ or larger is desirable. Such strain gradients have been realized experimentally, however, not exactly in the configuration proposed here [14, 15]. The strength of the confining potential is in this case $D = 10^{-15} N/m$ which corresponds roughly to an electric field of $1V/m$ for a sample of $60\mu m$. In systems with higher spin-orbit coupling, C_3 would be larger, and the strain gradient field would create a larger gap between the Landau levels.

We now turn to the question of the many-body wave function in the presence of interactions. For our system this is very suggestive, as the wave function incorporates both holomorphic and anti-holomorphic coordinates, by contrast to the pure holomorphic Laughlin states. Let the up-spin coordinates be z_i while the down-spin coordi-

nates be the w_i . z_i enter in holomorphic form in the wave function whereas w_i enter anti-holomorphically. While if the spin-up and spin-down electrons would lie in separate bi-layers the many-body wave function would be just $\prod_{i<j}(z_i - z_j)^m \prod_{k<l}(w_k^* - w_l^*)^m e^{-\frac{1}{2}(\sum_i z_i z_i^* + \sum_k w_k w_k^*)}$, where m is an odd integer. Since the particles in our state reside in the same quantum well and may possibly experience the additional interaction between the different spin states, a more appropriate wave function is:

$$\psi(z_i, w_i) = \prod_{i<j}(z_i - z_j)^m \prod_{k<l}(w_k^* - w_l^*)^m \prod_{r,s}(z_r - w_s^*)^n e^{-\frac{1}{2}(\sum_i z_i z_i^* + \sum_k w_k w_k^*)} \quad (9)$$

The above wave function is symmetric upon the interchange $z \leftrightarrow w^*$ reflecting the spin- \uparrow chiral - spin- \downarrow anti-chiral symmetry. This wave function is of course analogous to the Halperin's wave function of two different spin states [16]. The key difference is that the two different spin states here experience the opposite directions of magnetic fields.

Many profound topological properties of the quantum Hall effect are captured by the Chern-Simons-Landau-Ginzburg theory[17]. While the usual spin orbit coupling for spin-1/2 systems is T -invariant but P -breaking, our spin-orbit coupling is also P -invariant due to the strain gradient. The low energy field theory of the spin Hall liquid is hence a double Chern-Simons theory with the action:

$$S = \frac{\nu}{4\pi} \int \epsilon^{\mu\nu\rho} a_\mu \partial_\nu a_\rho - \frac{\nu}{4\pi} \int \epsilon^{\mu\nu\rho} c_\mu \partial_\nu c_\rho \quad (10)$$

where the a_μ and c_μ fields are associated with the left and right movers of our theory while ν is the filling factor. The fractional charge and statistics of the quasiparticle follow easily from this Chern-Simons action. Essentially, the two Chern-Simons terms have the same filling factor ν and hence the Hilbert space is not the tensor product of any two algebras, but of two identical ones. This is a mathematical statement of the fact that one can insert an up or down electron in the system with the same probability. Such special theories avoids the chiral anomaly [18] and their Berry phases have been recently proposed as preliminary examples of topological quantum computation [18]. It is refreshing to see that such abstract mathematical models can be realized in conventional semiconductors.

A similar situation of Landau levels without magnetic field arises in rotating BECs where the mean field Hamiltonian is similar to either H_\uparrow or H_\downarrow . In the limit of rapid rotation, the condensate expands and becomes effectively two-dimensional. The L_z term is induced by the rotation vector Ω [19]. The LLL behavior is achieved when the rotation frequency reaches a specific value analogous to the case $R \approx 2$ in our Hamiltonian. In the BEC literature this is the so called mean-field quantum Hall limit

and the ground state wave function is Laughlin-type. In contrast to our case, the theory is still T breaking, the magnetic field is replaced by a rotation axial vector, and the lowest Landau level is chiral.

In conclusion we predict a new state of matter where a quantum spin Hall liquid is formed in conventional semiconductors with spin-orbit coupling. The quantum Landau levels are caused by the gradient of strain field, rather than the magnetic field. The new quantum spin Hall liquid state shares many emergent properties similar to the charge quantum Hall effect, however, unlike the charge quantum Hall effect, our system does not violate time reversal symmetry.

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